

RF AMPLIFIER

MODEL *TM6010PM*

Available as: TM6010PM, 4 Pin TO-8 (T4)
 TN6010PM, 4 Pin Surface Mount (SM3)
 FP6010PM, 4 Pin Flatpack (FP4)
 BX6010PM, Connectorized Housing (H1)

Features

- Superior Phase Noise Performance
- High Output Power: +23 dBm Typical
- High Third Order Intercept: +36 dBm Typical
- Low +10 volt Supply
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	5 - 500 MHz	5 - 500 MHz
Gain (dB)	14.5	13.0 Min.
Power @ 1 dB Comp. (dBm)	+23	+20 Min.
Reverse Isolation (dB)	-18	-15 Max.
VSWR In	<1.4:1	2.0:1 Max.
Out	<1.2:1	2.0:1 Max.
Noise Figure (dB)	4.6	6.0 Max.
Power Vdc	+10	+10
mA	145	150 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Typical Intermodulation Performance at 25 °C

Second Order Harmonic Intercept Point +56 dBm (Typ.)
 Second Order Two Tone Intercept Point +50 dBm (Typ.)
 Third Order Two Tone Intercept Point +36 dBm (Typ.)

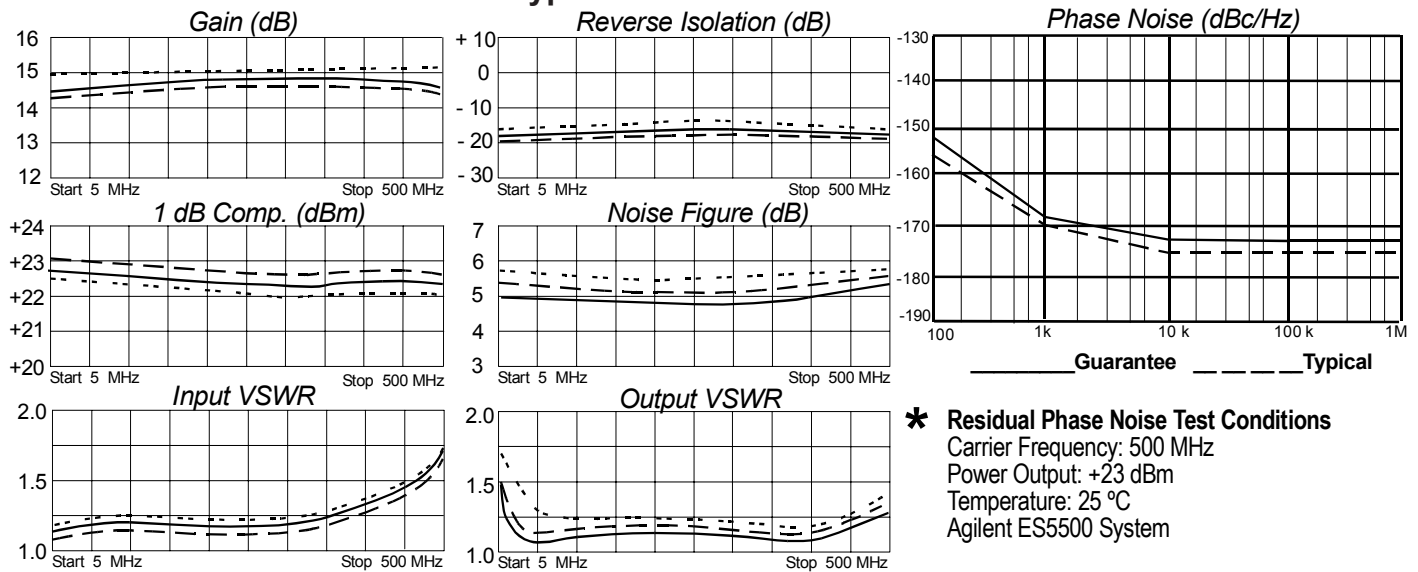
(Absolute) Maximum Ratings

Ambient Operating Temperature -55°C to +100 °C
 Storage Temperature -62°C to +125 °C
 Case Temperature +125 °C
 DC Voltage +12 volts
 Continuous RF Input Power +13 dBm
 Short Term RF Input Power 50 mW (1 Minute Max.)
 Maximum Peak Power 0.5 Watt (3 µsec Max.)

Guaranteed Phase Noise Performance (dBc/Hz) *

Frequency	Typical	Guaranteed
100 Hz	-156	-152
1 kHz	-170	-168
10 kHz	-175	-172
100 kHz	-175	-172
1 MHz	-175	-172

Typical Performance Data



* Residual Phase Noise Test Conditions
 Carrier Frequency: 500 MHz
 Power Output: +23 dBm
 Temperature: 25 °C
 Agilent ES5500 System

Legend ——— +25 °C - - - - +85 °C ······ -55 °C

Linear S-Parameters

FREQ. MHz	S11		S21		S12		S22	
	Mag	Deg	Mag	Deg	Mag	Deg	Mag	Deg
5	.23	-41	5.86	-163	.08	19	.27	86
100	.13	80	5.46	159	.11	3	.05	23
200	.40	24	5.51	137	.12	3	.04	23
300	.58	-31	5.50	114	.14	2	.04	45
400	.10	-91	5.53	90	.15	-1	.08	71
500	.20	-137	5.45	64	.17	-9	.17	66

